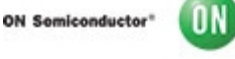


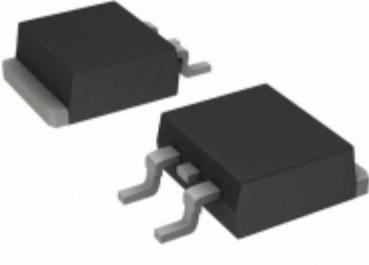










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|   | <h2 style="color: red;">FQB8N60CFTM</h2> <p>Hersteller-Teilenummer: FQB8N60CFTM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 6.26A D2PAK</p> <p>Datenblätter:  FQB8N60CFTM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10670 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | FQB8N60CFTM |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | MOSFET N-CH 600V 6.26A D2PAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 10670 pcs Stock |
| Serie | FRFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB |
| Supplier Device-Gehäuse | D ² PAK (TO-263AB) |
| Verlustleistung (max) | 147W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 600V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 6.26A (Tc) |
| Rds On (Max) @ Id, Vgs | 1.5 Ohm @ 3.13A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 36nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1255pF @ 25V |
| Verpackung | Tape & Reel (TR) |


FQB8N60CFTM ist neu im Original, Suche FQB8N60CFTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB8N60CFTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB8N60CFTM: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|---|---|
|  <p>FQB8N25TM Fairchild/ON Semiconductor MOSFET N-CH 250V 8A D2PAK</p> |  <p>FQB8N60CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.5A D2PAK</p> |  <p>FQB8N60CS Fairchild/ON Semiconductor FQB8N60CS FAIRCHILD</p> |  <p>FQB8N60CFTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 6.26A D2PAK</p> |
|  <p>FQB8N60CF FSC FSC TO-263</p> |  <p>FQB8N60CTM-WS AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7.5A</p> |  <p>FQB8N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 8A D2PAK</p> |  <p>FQB8N60 FAIRCHILD FQB8N60 FAIRCHILD</p> |

heiße Teile

Mehr

| | | | | |
|--|--|---|---|---|
|  FQB6N70TM |  FQB6N90TM |  FQB6N90TM_AM002 |  FQB6N90TM_AM002 |  FQB7042FB |
|  FQB7045FB |  FQB70N03 |  FQB70N06 |  FQB70N08 |  FQB70N10TM |
|  FQB7N10L |  FQB7N20L |  FQB7N60TM |  FQB7N60TM |  FQB7N65C |
|  FQB7N65CTM |  FQB7N65CTM |  FQB7P20TM |  FQB7P20TM |  FQB85N06 |
|  FQB85N06TM |  FQB8N25TM |  FQB8N25TM |  FQB8N60C |  FQB8N60CFTM |
|  FQB8N60CTM |  FQB8N60CTM |  FQB8N60TM |  FQB8N90CTM |  FQB8N90CTM |
|  FQB8P10TM |  FQB8P10TM |  FQB8P10TM-NL |  FQB9N08L |  FQB9N08LTM |
|  FQB9N08LTM |  FQB9N25C |  FQB9N25CTM |  FQB9N25CTM |  FQB9N25TM |
|  FQB9N25TM |  FQB9N50C |  FQB9N50CFTM |  FQB9N50CFTM |  FQB9N50CTM |
|  FQB9N50CTM |  FQB9N50TM |  FQB9N50TM |  FQB9P25TM |  FQB9P25TM |

Contact us: Info@Y-IC.com

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